Diode Semiconductor Device - Page 1 of 1



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Inclos	ure Material:
Glass	
Overa	I Length:
0.300 i	nches
Termiı	nal Length:
1.000 i	nches
Overa	Il Diameter:
0.107 i	nches
Joint B	Electronic Device Engineering Council/jedec/case Outline Designation:
Do-7	
Mount	ing Method:
Termir	al
Featur	es Provided:
Herme	tically sealed case
Semic	onductor Material:
Silicon	
Voltag	e Rating In Volts Per Characteristic:
225.0	reverse voltage, peak
Currer	nt Rating Per Characteristic:
0.40 aı	nperes source cutoff current preset
Power	Rating Per Characteristic:
0.6 wa	tts small-signal input power, common-collector preset
Termiı	nal Type And Quantity:
2 unins	sulated wire lead
Shelf I	_ife:
N/a	
Unit O	f Measure:
Demili	tarization:
No	
Fiig:	
A110a	0